查询TLP3542供应商



TLP3542

TENTATIVE

TOSHIBA PHOTOCOUPLER PHOTO RELAY

TLP3542

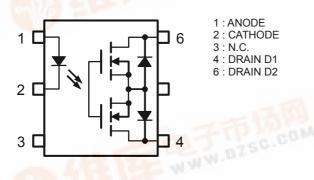
TESTERS DATA RECORDING EQUIPMENT MEASURING EQUIPMENT

The TOSHIBA TLP3542 series consist of a aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a plastic DIP package.

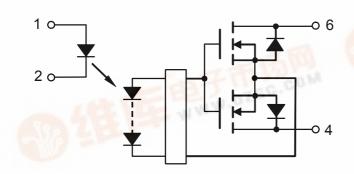
The TLP3452 series are a bi-directional switch, which can replace mechanical relays in many applications.

- 6 pin DIP (DIP6)
- 1-Form-A
- Peak Off-State Voltage : 60 V (MIN.)
- Trigger LED Current : 3 mA (MAX.)
- On-State Current : 2.5 A (MAX.)
- On-State Resistance : 100 m Ω (MAX.)
- Isolation Voltage
- •
- ige : 2500 Vrms (MIN.)

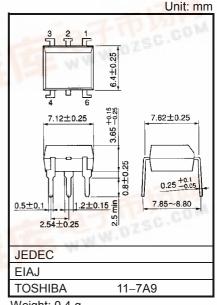
PIN CONFIGURATION (TOL VIEW)



SCHEMATIC









MAXIMUM RATINGS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	RATING	UNIT
LED	Forward Current	١ _F	30	mA
	Forward Current Derating (Ta $\ge 25^{\circ}$ C)	∆I _F /°C	-0.3	mA/°C
	Peak Forward Current (100 μ s pulse, 100 pps)	I _{FP}	1	А
	Reverse Voltage	V _R	5	V
	Junction Temperature	Tj	125	°C
DETECTOR	Off-State Output Terminal Voltage	V _{OFF}	60	V
	On-State Current	I _{ON}	2.5	А
ETE	On-State Current Derating(Ta \ge 40°C)	∆l _{ON} /°C	22	mA/°C
	Junction Temperature	Tj	125	°C
Storage Temperature Range		T _{stg}	-40~125	°C
Operating Temperature Range		T _{opr}	-20~85	°C
Lead	Lead Soldering Temperature (10 s)		260	°C
Isolat	ion Voltage (AC, 1 minute, R.H. \leq 60%) (NOTE1)	BVS	2500	Vrms

(NOTE1) :Device considered a two-terminal device : Pins 1, 2 and 3 shorted together, and pins 4 and 6 shorted together.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{DD}	_	_	48	V
Forward Current	١ _F	10	_	20	mA
On-State Current	I _{ON}	_	_	2.5	А
Operating Temperature	T _{opr}	25		60	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	Forward Voltage	VF	I _F = 10 mA	1.18	1.33	1.48	V
LED	Reverse Current	I _R	$V_R = 5 V$	_	_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz	_	30	_	pF
DETECTOR	Off-State Current I _{OFF}	lorr	V _{OFF} = 20 V, Ta = 25°C	_	0.1	1.5	nA
		V _{OFF} = 60 V, Ta = 25°C	_	1.0	10	nA	
	Capacitance	C _{OFF}	V = 0, f = 1 MHz	_	400	600	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I _{FT}	I _{ON} = 1.0 A		1	3	mA
Return LED Current	I _{FC}	I _{OFF} = 10 μA	0.1			mA
On-State Resistance	R _{ON}	$I_{ON} = 2.0 \text{ A}, I_F = 10 \text{ mA}, t = 10 \text{ ms}$		65	100	mΩ

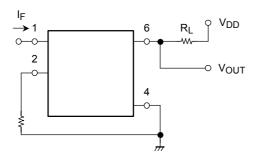
ISOLATION CHARACTERISTICS (Ta = 25°C)

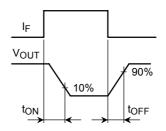
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	CS	$V_{S} = 0 V$, f = 1 MHz	_	0.8	_	pF
Isolation Resistance	R _S	$V_S = 500 \text{ V}, \text{ R.H.} \leq 60\%$	$5 imes 10^{10}$	10 ¹⁴	_	Ω
		AC, 1 minute	2500	_	_	Vrms
Isolation Voltage	BVS	AC, 1 second (in oil)	_	5000	_	VIIIIS
		DC, 1 minute (in oil)	_	5000	_	Vdc

SWITCHING CHARACTERISTICS (Ta = 25°C)

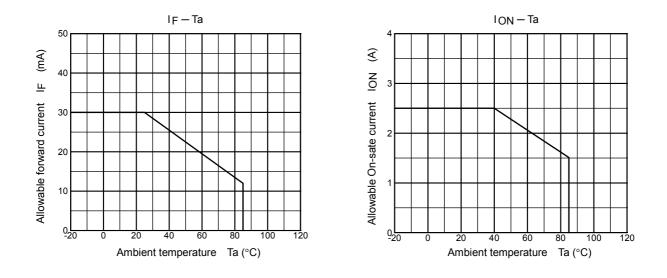
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Turn-on Time	t _{ON}	$R_L = 200 \Omega$ (NOTE 2)	_	1.0	1.5	ms
Turn-off Time	t _{OFF}	$V_{DD} = 20 \text{ V}, \text{ I}_{\text{F}} = 10 \text{ mA}$		0.2	0.4	1115

(NOTE 2) : SWITCHING TIME TEST CIRCUIT





TOSHIBA



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